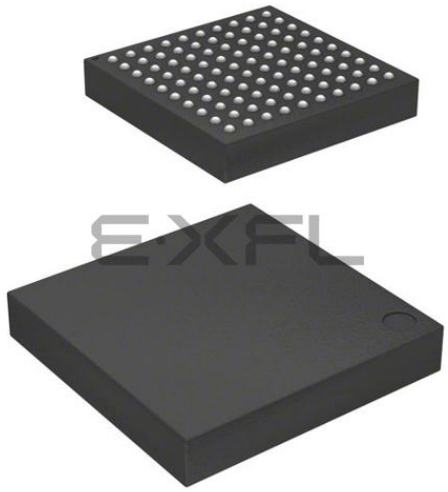
Renesas Electronics America Inc - R7FS3A17C2A01CLJ#AC0 Datasheet



Welcome to E-XFL.COM

What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	CANbus, EBI/EMI, I²C, MMC/SD, QSPI, SCI, SSIE, SPI, UART/USART, USB
Peripherals	DMA, LCD, LVD, POR, PWM, WDT
Number of I/O	84
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	8K x 8
RAM Size	192K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 25x14b; D/A 1x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-TFLGA
Supplier Device Package	100-TFLGA (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r7fs3a17c2a01clj-ac0

Table 1.8 Communication interfaces (2 of 2)

Feature	Functional description
Controller Area Network (CAN) Module	The Controller Area Network (CAN) module provides functionality to receive and transmit data using a message-based protocol between multiple slaves and masters in electromagnetically noisy applications. The CAN module complies with the ISO 11898-1 (CAN 2.0A/CAN 2.0B) standard and supports up to 32 mailboxes, which can be configured for transmission or reception in normal mailbox and FIFO modes. Both standard (11-bit) and extended (29-bit) messaging formats are supported. See section 31, Controller Area Network (CAN) Module in the User's Manual.
USB 2.0 Full-Speed Module (USBFS)	The USBFS is a USB controller that can operate as a host controller or device controller. The module supports full-speed and low-speed (only for the host controller) transfer as defined in the Universal Serial Bus specification 2.0. The module has an internal USB transceiver and supports all of the transfer types defined in the Universal Serial Bus specification 2.0. The USB has buffer memory for data transfer, providing a maximum of 10 pipes. Pipes 1 to 9 can be assigned any endpoint number based on the peripheral devices used for communication or based on the your system. The MCU supports revision 1.2 of the Battery Charging specification. Because the MCU can be powered at 5 V, the USB LDO regulator provides the internal USB transceiver power supply at 3.3 V. See section 28, USB 2.0 Full-Speed Module (USBFS) in the User's Manual.
SD/MMC Host Interface (SDHI)	The Secure Digital Host Interface (SDHI) and MultiMediaCard (MMC) interface provide the functionality needed to connect a variety of external memory cards to the MCU. The SDHI supports both 1-bit and 4-bit buses for connecting different memory cards that support SD, SDHC, and SDXC formats. When developing host devices that are compliant with the SD specifications, you must comply with the SD Host/Ancillary Product License Agreement (SD HALA). The MMC interface supports 1-bit, 4-bit, and 8-bit MMC buses that provide eMMC 4.51 (JEDEC Standard JESD 84-B451) device access. This interface also provides backward compatibility and support for high-speed SDR transfer modes. See section 36, SD/MMC Host Interface (SDHI) in the User's Manual.

Table 1.9 Analog

Feature	Functional description
14-bit A/D Converter (ADC14)	A 14-bit successive approximation A/D converter is provided. Up to 28 analog input channels are selectable. Temperature sensor output and internal reference voltage are selectable for conversion. The A/D conversion accuracy is selectable from 12-bit and 14-bit conversion making it possible to optimize the tradeoff between speed and resolution in generating a digital value. See section 38, 14-Bit A/D Converter (ADC14) in the User's Manual.
12-bit D/A Converter (DAC12)	The 12-bit D/A converts data and includes an output amplifier. See section 39, 12-Bit D/A Converter (DAC12) in the User's Manual.
8-bit D/A Converter (DAC8) (for ACMPLP)	The 8-bit D/A converts data and does not include an output amplifier (DAC8). The DAC8 is used only as the reference voltage for ACMPLP. See section 43, 8-Bit D/A Converter (DAC8) in the User's Manual.
Temperature Sensor (TSN)	The on-chip temperature sensor determines and monitors the die temperature for reliable operation of the device. The sensor outputs a voltage directly proportional to the die temperature, and the relationship between the die temperature and the output voltage is linear. The output voltage is provided to the ADC14 for conversion and can be further used by the end application. See section 40, Temperature Sensor (TSN) in the User's Manual.
Low-Power Analog Comparator (ACMPLP)	The analog comparator compares the reference input voltage and analog input voltage. The comparison result can be read through software and also be output externally. The reference input voltage can be selected from an input to the CMPREFi (i = 0, 1) pin, an internal 8-bit D/A converter output, or the internal reference voltage (Vref) generated internally in the MCU. The ACMPLP response speed can be set before starting an operation. Setting the High-speed mode decreases the response delay time, but increases current consumption. Setting the Low-speed mode increases the response delay time, but decreases current consumption. See section 42, Low Power Analog Comparator (ACMPLP) in the User's Manual.
Operational Amplifier (OPAMP)	The operational amplifier amplifies small analog input voltages and outputs the amplified voltages. A total of four differential operational amplifier units with two input pins and one output pin are provided. See section 41, Operational Amplifier (OPAMP) in the User's Manual.

Table 1.10 Human machine interfaces

Feature	Functional description
Segment LCD Controller (SLCDC)	The SLCDC provides the following functions: • Waveform A or B selectable • The LCD driver voltage generator can switch between an internal voltage boosting method, a capacitor split method, and an external resistance division method • Automatic output of segment and common signals based on automatic display data register read • The reference voltage generated when operating the voltage boost circuit can be selected in 16 steps (contrast adjustment) • The LCD can be made to blink. See section 48, Segment LCD Controller (SLCDC) in the User's Manual.
Capacitive Touch Sensing Unit (CTSU)	The Capacitive Touch Sensing Unit (CTSU) measures the electrostatic capacitance of the touch sensor. Changes in the electrostatic capacitance are determined by software, which enables the CTSU to detect whether a finger is in contact with the touch sensor. The electrode surface of the touch sensor is usually enclosed with an electrical insulator so that fingers do not come into direct contact with the electrodes. See section 44, Capacitive Touch Sensing Unit (CTSU) in the User's Manual.

Table 1.11 Data processing

Feature	Functional description
Cyclic Redundancy Check (CRC) Calculator	The CRC calculator generates CRC codes to detect errors in the data. The bit order of CRC calculation results can be switched for LSB-first or MSB-first communication. Additionally, various CRC-generating polynomials are available. The snoop function allows monitoring reads from and writes to specific addresses. This function is useful in applications that require CRC code to be generated automatically in certain events, such as monitoring writes to the serial transmit buffer and reads from the serial receive buffer. See section 34, Cyclic Redundancy Check (CRC) Calculator in the User's Manual.
Data Operation Circuit (DOC)	The Data Operation Circuit (DOC) compares, adds, and subtracts 16-bit data. See section 45, Data Operation Circuit (DOC) in the User's Manual.

Table 1.12 Security

Feature	Functional description
Secure Crypto Engine 5 (SCE5)	• Security algorithm: - Symmetric algorithm: AES • Other support features: - TRNG (True Random Number Generator) - Hash-value generation: GHASH.

2. Electrical Characteristics

Unless otherwise specified, the electrical characteristics of the MCU are defined under the following conditions:

VCC*1 = AVCC0 = VCC_USB*2 = VCC_USB_LDO*2 = 1.6 to 5.5 V, VRERH = VREFH0 = 1.6 to AVCC0, VBATT = 1.6 to 3.6 V, VSS = AVSS0 = VREFL = VREFL0 = VSS_USB = 0 V, Ta = T_{opr}.

Note 1. The typical condition is set to VCC = 3.3V.
Note 2. When USBFS is not used.

Figure 2.1 shows the timing conditions.

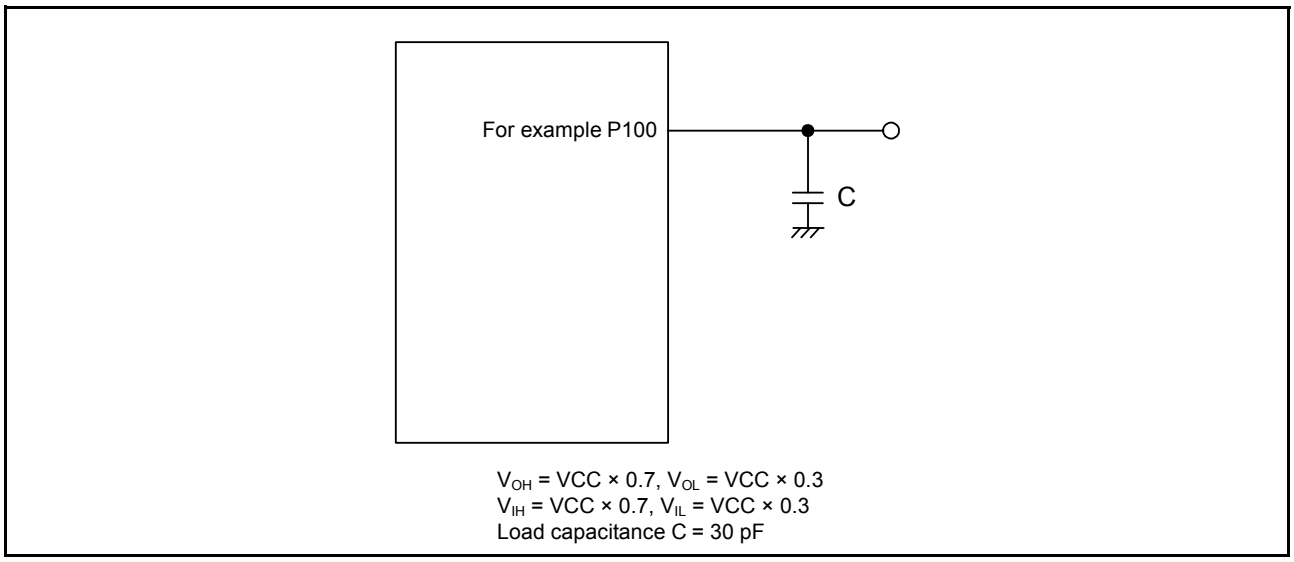


Figure 2.1 Input or output timing measurement conditions

The measurement conditions of timing specifications in each peripheral are recommended for the best peripheral operation. However, make sure to adjust driving abilities of each pin to meet your conditions.

Each function pin used for the same function must select the same drive ability. If the I/O drive ability of each function pin is mixed, the AC specification of each function is not guaranteed.

Table 2.5 I/O V_{IH}, V_{IL} (2)

Conditions: VCC = AVCC0 = VCC_USB = VCC_USB_LDO = 1.6 to 2.7 V, VBATT = 1.6 to 3.6 V, VSS = AVSS0 = 0 V

Parameter		Symbol	Min	Typ	Max	Unit	Test conditions
Schmitt trigger input voltage	RES, NMI Peripheral input pins	V_{IH}	VCC × 0.8	-	-	V	-
		V_{IL}	-	-	VCC × 0.2		
		ΔV_T	VCC × 0.01	-	-		
Input voltage (except for Schmitt trigger input pin)	5V-tolerant ports*1	V_{IH}	VCC × 0.8	-	5.8		
		V_{IL}	-	-	VCC × 0.2		
	P914, P915	V_{IH}	VCC_USB × 0.8	-	VCC_USB + 0.3		
		V_{IL}	-	-	VCC_USB × 0.2		
	P000 to P015	V_{IH}	AVCC0 × 0.8	-	-		
		V_{IL}	-	-	AVCC0 × 0.2		
	EXTAL D00 to D15 Input ports pins except for P000 to P015, P914, P915	V_{IH}	VCC × 0.8	-	-		
		V_{IL}	-	-	VCC × 0.2		
When V_{BATT} power supply is selected	P402, P403, P404	V_{IH}	V_{BATT} × 0.8	-	V_{BATT} + 0.3		
		V_{IL}	-	-	V_{BATT} × 0.2		
		ΔV_T	V_{BATT} × 0.01	-	-		

Note 1. P205, P206, P400 to P404, P407, P408, P511, P512 (total 11 pins)

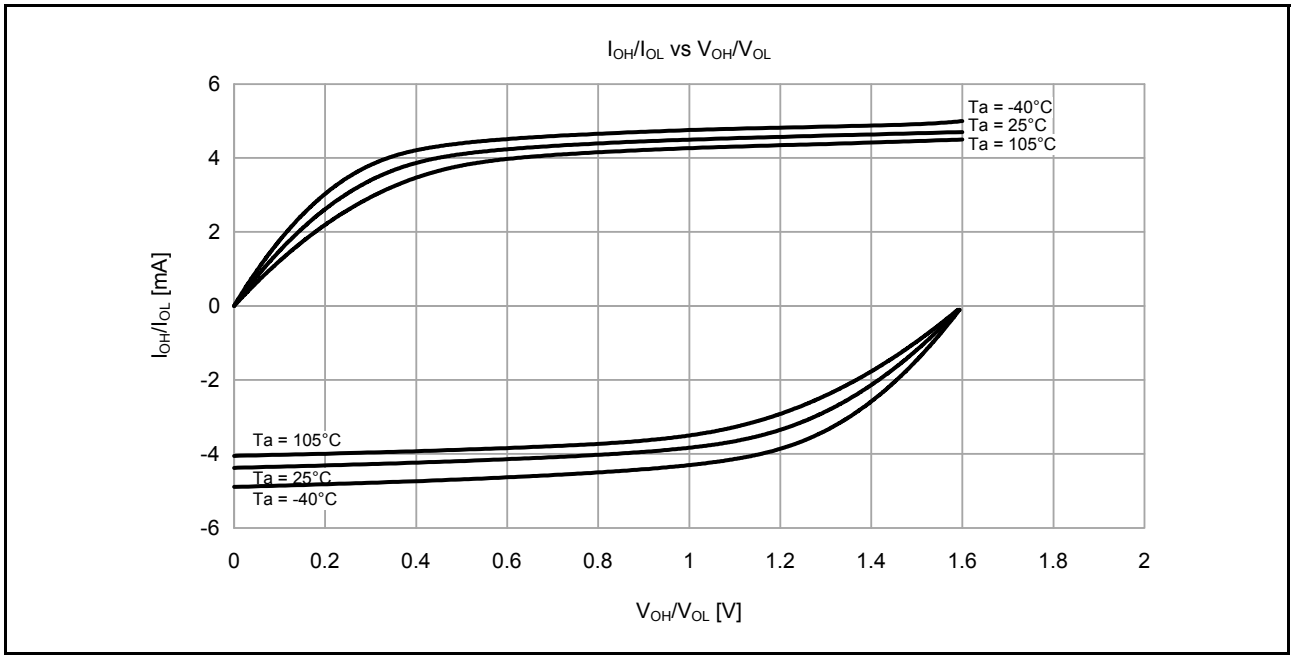


Figure 2.8 **V_{OH}/V_{OL} and I_{OH}/I_{OL} temperature characteristics at VCC = 1.6 V when middle drive output is selected (reference data)**

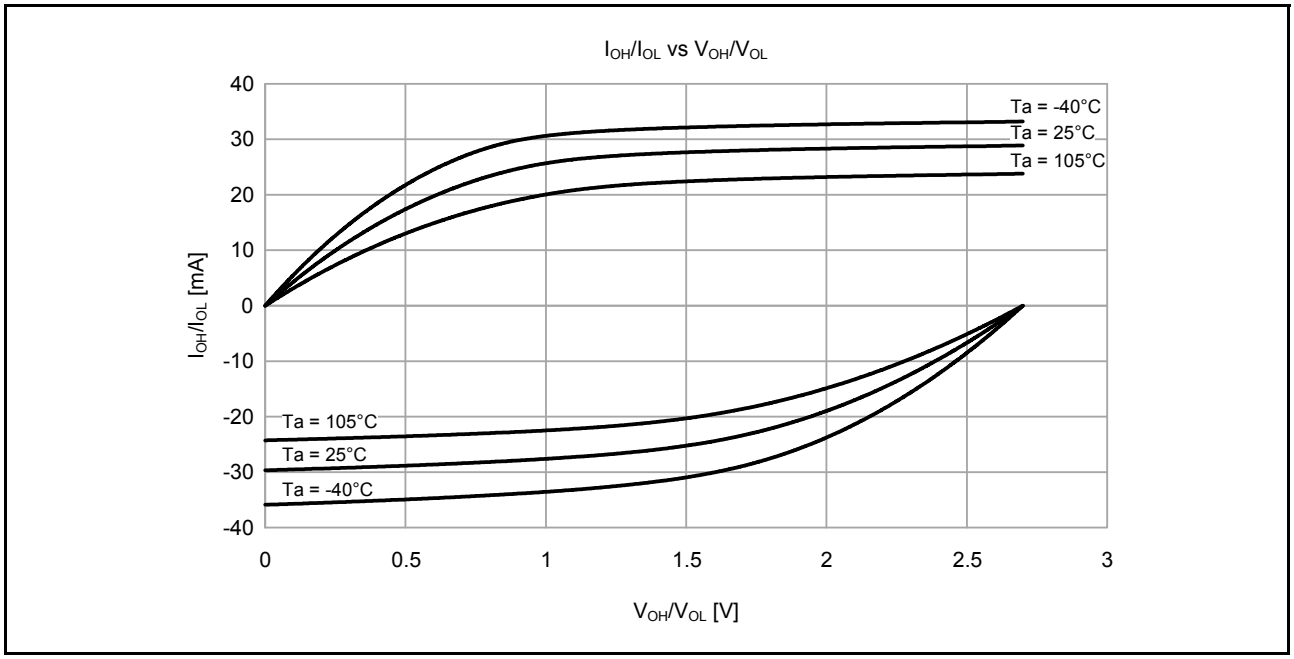
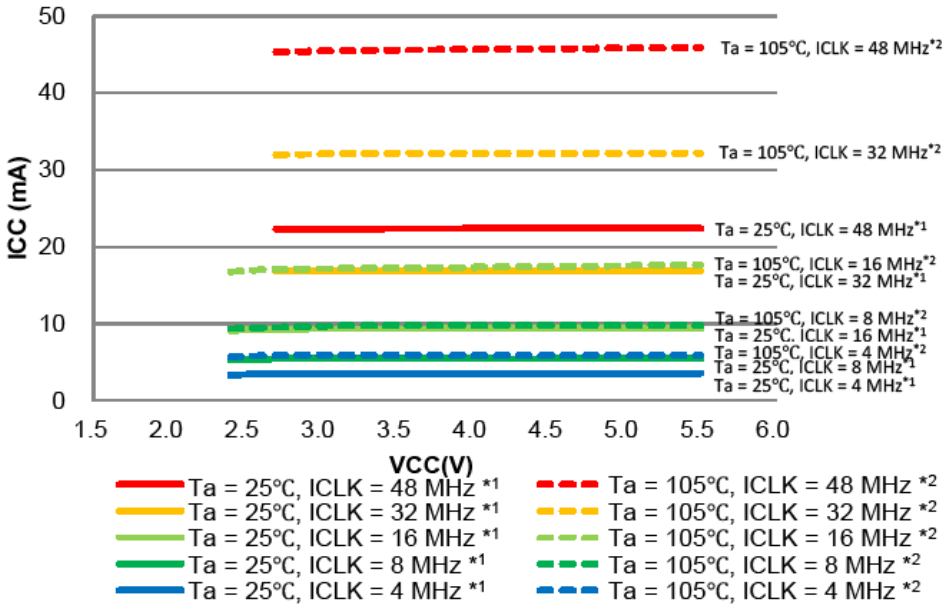


Figure 2.9 **V_{OH}/V_{OL} and I_{OH}/I_{OL} temperature characteristics at VCC = 2.7 V when middle drive output is selected (reference data)**

Table 2.11 Operating and standby current (1) (2 of 2)
Conditions: VCC = AVCC0 = 1.6 to 5.5 V

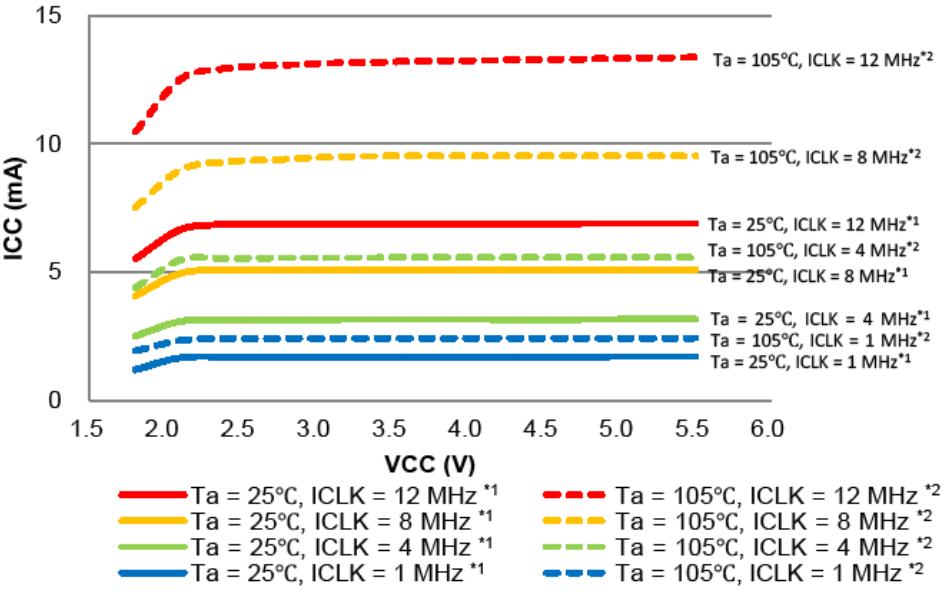
Parameter					Symbol	Typ*10	Max	Unit	Test conditions
Supply current*1	Low-speed mode*3	Normal mode	All peripheral clocks disabled, while (1) code executing from flash*5	ICLK = 1 MHz	I_{CC}	0.4	-	mA	*7
			All peripheral clocks disabled, CoreMark code executing from flash*5	ICLK = 1 MHz		0.6	-		
			All peripheral clocks enabled, while (1) code executing from flash*5	ICLK = 1 MHz		1.1	-		*8
			All peripheral clocks enabled, code executing from SRAM*5	ICLK = 1 MHz		-	2.6		
		Sleep mode	All peripheral clocks disabled*5	ICLK = 1 MHz		0.3	-		*7
			All peripheral clocks enabled*5	ICLK = 1 MHz		1.0	-		*8
	Low-voltage mode*3	Normal mode	All peripheral clocks disabled, while (1) code executing from flash*5	ICLK = 4 MHz	I_{CC}	2.2	-	mA	*7
			All peripheral clocks disabled, CoreMark code executing from flash*5	ICLK = 4 MHz		3.3	-		
			All peripheral clocks enabled, while (1) code executing from flash*5	ICLK = 4 MHz		3.7	-		*8
			All peripheral clocks enabled, code executing from SRAM*5	ICLK = 4 MHz		-	10.0		
		Sleep mode	All peripheral clocks disabled*5	ICLK = 4 MHz		1.7	-		*7
			All peripheral clocks enabled*5	ICLK = 4 MHz		3.2	-		*8
	Subosc-speed mode*4	Normal mode	All peripheral clocks disabled, while (1) code executing from flash*5	ICLK = 32.768 kHz	I_{CC}	10.0	-	µA	*8
			All peripheral clocks enabled, while (1) code executing from flash*5	ICLK = 32.768 kHz		17.9	-		
			All peripheral clocks enabled, code executing from SRAM*5	ICLK = 32.768 kHz		-	154.0		
		Sleep mode	All peripheral clocks disabled*5	ICLK = 32.768 kHz		6.3	-		
			All peripheral clocks enabled*5	ICLK = 32.768 kHz		14.0	-		

Note 1. Supply current values do not include output charge/discharge current from all pins. The values apply when internal pull-up MOSs are in the off state.
Note 2. The clock source is HOCO.
Note 3. The clock source is MOCO.
Note 4. The clock source is the sub-clock oscillator.
Note 5. This does not include BGO operation.
Note 6. This is the increase for programming or erasure of the flash memory for data storage during program execution.
Note 7. FCLK, BCLK, PCLKA, PCLKB, PCLKC, and PCLKD are set to divided by 64.
Note 8. FCLK, BCLK, PCLKA, PCLKB, PCLKC, and PCLKD are the same frequency as that of ICLK.
Note 9. FCLK, BCLK, and PCLKB are set to divided by 2 and PCLKA, PCLKC, and PCLKD are the same frequency as that of ICLK.
Note 10. VCC = 3.3 V.



Note 1. All peripheral operations except any BGO operation are operating normally. This is the average of the actual measurements of the sample cores during product evaluation.
Note 2. All peripheral operations except any BGO operation are operating at maximum. This is the average of the actual measurements for the upper-limit samples during product evaluation.

Figure 2.17 Voltage dependency in high-speed mode (reference data)



Note 1. All peripheral operations except any BGO operation are operating normally. This is the average of the actual measurements of the sample cores during product evaluation.
Note 2. All peripheral operations except any BGO operation are operating at maximum. This is the average of the actual measurements for the upper-limit samples during product evaluation.

Figure 2.18 Voltage dependency in middle-speed mode (reference data)

2.3 AC Characteristics

2.3.1 Frequency

Table 2.17 Operation frequency value in high-speed operating mode

Conditions: VCC = AVCC0 = 2.4 to 5.5 V

Parameter			Symbol	Min	Typ	Max*5	Unit
Operation frequency	System clock (ICLK)*4	2.7 to 5.5 V	f	0.032768	-	48	MHz
		2.4 to 2.7 V		0.032768	-	16	
	FlashIF clock (FCLK)*1, *2, *4	2.7 to 5.5 V		0.032768	-	32	
		2.4 to 2.7 V		0.032768	-	16	
	Peripheral module clock (PCLKA)*4	2.7 to 5.5 V		-	-	48	
		2.4 to 2.7 V		-	-	16	
	Peripheral module clock (PCLKB)*4	2.7 to 5.5 V		-	-	32	
		2.4 to 2.7 V		-	-	16	
	Peripheral module clock (PCLKC)*3, *4	2.7 to 5.5 V		-	-	64	
		2.4 to 2.7 V		-	-	16	
	Peripheral module clock (PCLKD)*4	2.7 to 5.5 V		-	-	64	
		2.4 to 2.7 V		-	-	16	
	External bus clock (BCLK)*4	2.7 to 5.5 V		-	-	24	
		2.4 to 2.7 V		-	-	16	
	EBCLK pin output	2.7 to 5.5 V		-	-	12	
		2.4 to 2.7 V		-	-	8	

Note 1. The lower-limit frequency of FCLK is 1 MHz while programming or erasing the flash memory. When using FCLK for programming or erasing the flash memory at below 4 MHz, the frequency can be set to 1 MHz, 2 MHz, or 3 MHz. A non-integer frequency such as 1.5 MHz cannot be set.

Note 2. The frequency accuracy of FCLK must be ±3.5% while programming or erasing the flash memory. Confirm the frequency accuracy of the clock source.

Note 3. The lower-limit frequency of PCLKC is 4 MHz at 2.4 V or above and 1 MHz at below 2.4 V when the 14-bit A/D converter is in use.

Note 4. See section 9, Clock Generation Circuit in the User's Manual for the relationship of frequencies between ICLK, PCLKA, PCLKB, PCLKC, PCLKD, FCLK, and BCLK.

Note 5. The maximum value of operation frequency does not include the internal oscillator errors. The operation can be guaranteed with the errors of the internal oscillator. For details on the range for guaranteed operation, see Table 2.22, Clock timing.

Note 3. See section 9, Clock Generation Circuit in the User's Manual for the relationship of frequencies between ICLK, PCLKA, PCLKB, PCLKC, PCLKD, FCLK, and BCLK.
Note 4. The maximum value of operation frequency does not include the internal oscillator errors. The operation can be guaranteed with the errors of the internal oscillator. For details on the range for guaranteed operation, see Table 2.22, Clock timing.

Table 2.20 Operation frequency value in Low-voltage mode

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter			Symbol	Min	Typ	Max*5	Unit
Operation frequency	System clock (ICLK)*4	1.6 to 5.5 V	f	0.032768	-	4	MHz
	FlashIF clock (FCLK)*1, *2, *4	1.6 to 5.5 V		0.032768	-	4	
	Peripheral module clock (PCLKA)*4	1.6 to 5.5 V		-	-	4	
	Peripheral module clock (PCLKB)*4	1.6 to 5.5 V		-	-	4	
	Peripheral module clock (PCLKC)*3, *4	1.6 to 5.5 V		-	-	4	
	Peripheral module clock (PCLKD)*4	1.6 to 5.5 V		-	-	4	
	External bus clock (BCLK)*4	1.6 to 5.5 V		-	-	4	
	EBCLK pin output	1.8 to 5.5 V		-	-	4	
		1.6 to 1.8 V		-	-	2	

Note 1. The lower-limit frequency of FCLK is 1 MHz while programming or erasing the flash memory. When using FCLK for programming or erasing the flash memory at below 4 MHz, the frequency can be set to 1 MHz, 2 MHz, or 3 MHz. A non-integer frequency such as 1.5 MHz cannot be set.
Note 2. The frequency accuracy of FCLK must be ±3.5% while programming or erasing the flash memory. Confirm the frequency accuracy of the clock source.
Note 3. The lower-limit frequency of PCLKC is 4 MHz at 2.4 V or above and 1 MHz at below 2.4 V when the 14-bit A/D converter is in use.
Note 4. See section 9, Clock Generation Circuit in the User's Manual for the relationship of frequencies between ICLK, PCLKA, PCLKB, PCLKC, PCLKD, FCLK, and BCLK.
Note 5. The maximum value of operation frequency does not include errors of the internal oscillator. The operation can be guaranteed with the errors of the internal oscillator. For details on the range for guaranteed operation, see Table 2.22, Clock timing.

Table 2.21 Operation frequency value in Subosc-speed mode

Conditions: VCC = AVCC0 = 1.8 to 5.5 V

Parameter			Symbol	Min	Typ	Max	Unit
Operation frequency	System clock (ICLK)*3	1.8 to 5.5 V	f	27.8528	32.768	37.6832	kHz
	FlashIF clock (FCLK)*1, *3	1.8 to 5.5 V		27.8528	32.768	37.6832	
	Peripheral module clock (PCLKA)*3	1.8 to 5.5 V		-	-	37.6832	
	Peripheral module clock (PCLKB)*3	1.8 to 5.5 V		-	-	37.6832	
	Peripheral module clock (PCLKC)*2, *3	1.8 to 5.5 V		-	-	37.6832	
	Peripheral module clock (PCLKD)*3	1.8 to 5.5 V		-	-	37.6832	
	External bus clock (BCLK)*3	1.8 to 5.5 V		-	-	37.6832	
	EBCLK pin output	1.8 to 5.5 V		-	-	37.6832	

Note 1. Programming and erasing the flash memory are not possible.
Note 2. The 14-bit A/D converter cannot be used.
Note 3. See section 9, Clock Generation Circuit in the User's Manual for the relationship of frequencies between ICLK, PCLKA, PCLKB, PCLKC, PCLKD, FCLK, and BCLK.

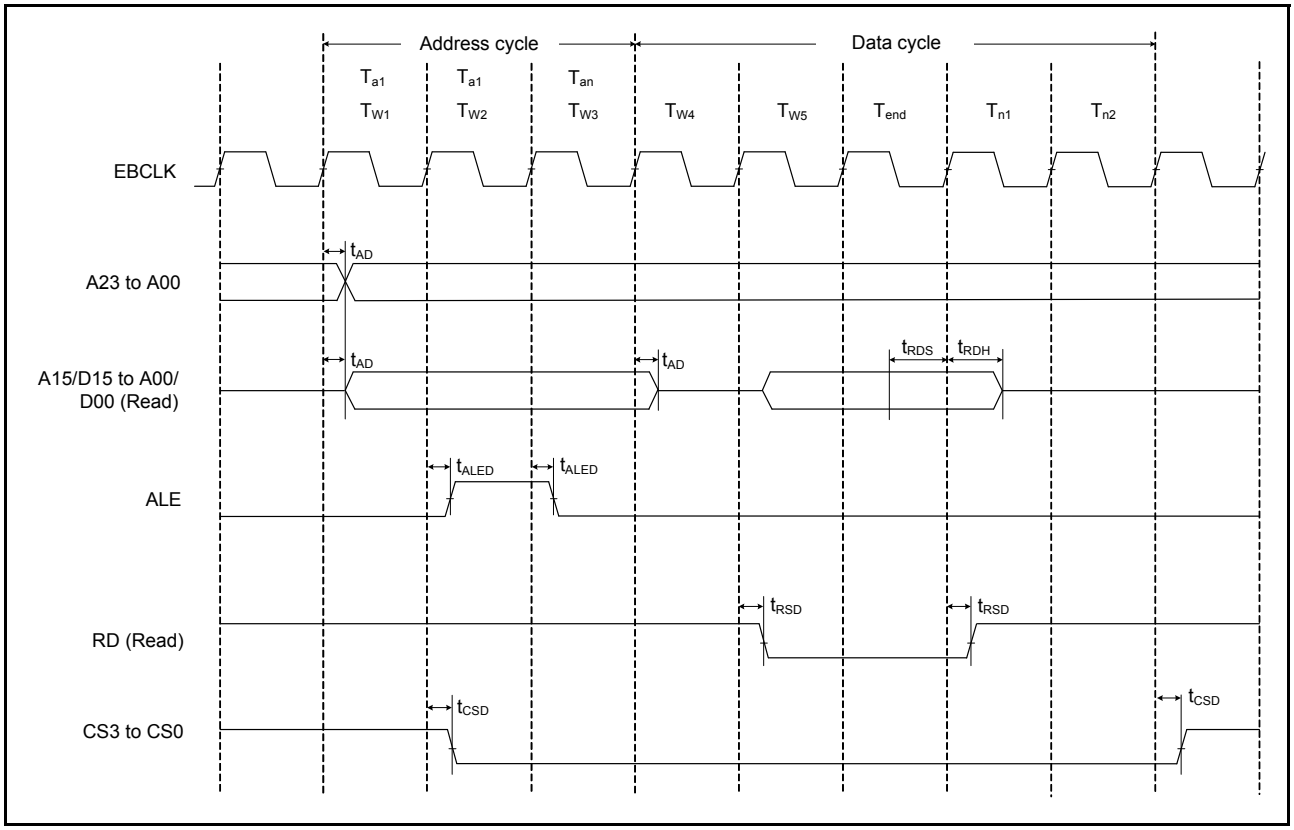


Figure 2.40 Address/data multiplexed bus read access timing

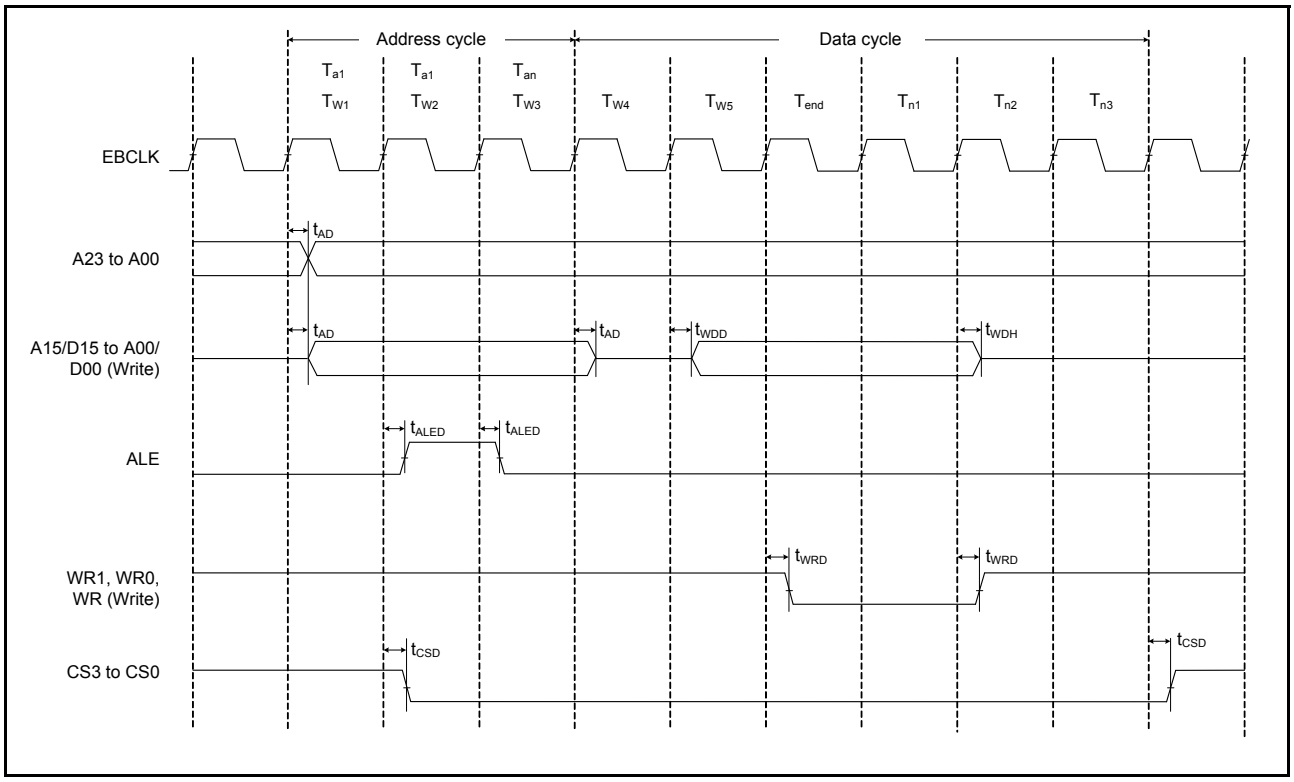


Figure 2.41 Address/data multiplexed bus write access timing

2.3.10 SPI Timing

Table 2.40 SPI timing (1 of 2)
Conditions: Middle drive output is selected in the Port Drive Capability in PmnPFS register

Parameter				Symbol	Min	Max	Unit*1	Test conditions
SPI	RSPCK clock cycle	Master		t_{SPcyc}	2*4	4096	t_{Pcyc}	Figure 2.61
		Slave			6	4096		
	RSPCK clock high pulse width	Master		t_{SPCKWH}	$(t_{SPcyc} - t_{SPCKR} - t_{SPCKF}) / 2 - 3$	-	ns	
		Slave			$3 \times t_{Pcyc}$	-		
	RSPCK clock low pulse width	Master		t_{SPCKWL}	$(t_{SPcyc} - t_{SPCKR} - t_{SPCKF}) / 2 - 3$	-	ns	
		Slave			$3 \times t_{Pcyc}$	-		
	RSPCK clock rise and fall time	Output	2.7 V or above	t_{SPCKr}, t_{SPCKf}	-	10	ns	
			2.4 V or above		-	15		
			1.8 V or above		-	20		
			1.6 V or above		-	30		
		Input			-	1	µs	
	Data input setup time	Master		t_{SU}	10	-	ns	Figure 2.62 to Figure 2.67
		Slave	2.4 V or above		10	-		
			1.8 V or above		15	-		
			1.6 V or above		20	-		
	Data input hold time	Master (RSPCK is PCLKA/2)		t_{HF}	0	-	ns	
		Master (RSPCK is other than above.)		t_H	t_{Pcyc}	-		
		Slave		t_H	20	-		
	SSL setup time	Master	1.8 V or above	t_{LEAD}	$-30 + N \times t_{Spcyc}$*2	-	ns	
			1.6 V or above		$-50 + N \times t_{Spcyc}$*2	-		
		Slave			$6 \times t_{Pcyc}$	-		
	SSL hold time	Master		t_{LAG}	$-30 + N \times t_{Spcyc}$*3	-		
		Slave			$6 \times t_{Pcyc}$	-		

Table 2.40 SPI timing (2 of 2)

Conditions: Middle drive output is selected in the Port Drive Capability in PmnPFS register

Parameter				Symbol	Min	Max	Unit*1	Test conditions
SPI	Data output delay	Master	2.7 V or above	t_{OD}	-	14	ns	Figure 2.62 to Figure 2.67
			2.4 V or above		-	20		
			1.8 V or above		-	25		
			1.6 V or above		-	30		
		Slave	2.7 V or above		-	50		
			2.4 V or above		-	60		
			1.8 V or above		-	85		
			1.6 V or above		-	110		
	Data output hold time	Master		t_{OH}	0	-	ns	
		Slave			0	-		
	Successive transmission delay	Master		t_{TD}	$t_{SPcyc} + 2 \times t_{Pcyc}$	$8 \times t_{SPcyc} + 2 \times t_{Pcyc}$	ns	
		Slave			$6 \times t_{Pcyc}$	-		
	MOSI and MISO rise and fall time	Output	2.7 V or above	t_{Dr}, t_{Df}	-	10	ns	
			2.4 V or above		-	15		
			1.8 V or above		-	20		
			1.6 V or above		-	30		
		Input			-	1	µs	
	SSL rise and fall time	Output	2.7 V or above	t_{SSLr}, t_{SSLf}	-	10	ns	
			2.4 V or above		-	15		
			1.8 V or above		-	20		
			1.6 V or above		-	30		
		Input			-	1	µs	
	Slave access time		2.4 V or above	t_{SA}	-	$2 \times t_{Pcyc} + 100$	ns	Figure 2.66 and Figure 2.67
			1.8 V or above		-	$2 \times t_{Pcyc} + 140$		
			1.6 V or above		-	$2 \times t_{Pcyc} + 180$		
	Slave output release time		2.4 V or above	t_{REL}	-	$2 \times t_{Pcyc} + 100$	ns	
			1.8 V or above		-	$2 \times t_{Pcyc} + 140$		
			1.6 V or above		-	$2 \times t_{Pcyc} + 180$		

Note 1. t_{Pcyc}: PCLKA cycle.
Note 2. N is set as an integer from 1 to 8 by the SPCKD register.
Note 3. N is set as an integer from 1 to 8 by the SSLND register.
Note 4. The upper limit of RSPCK is 16 MHz.

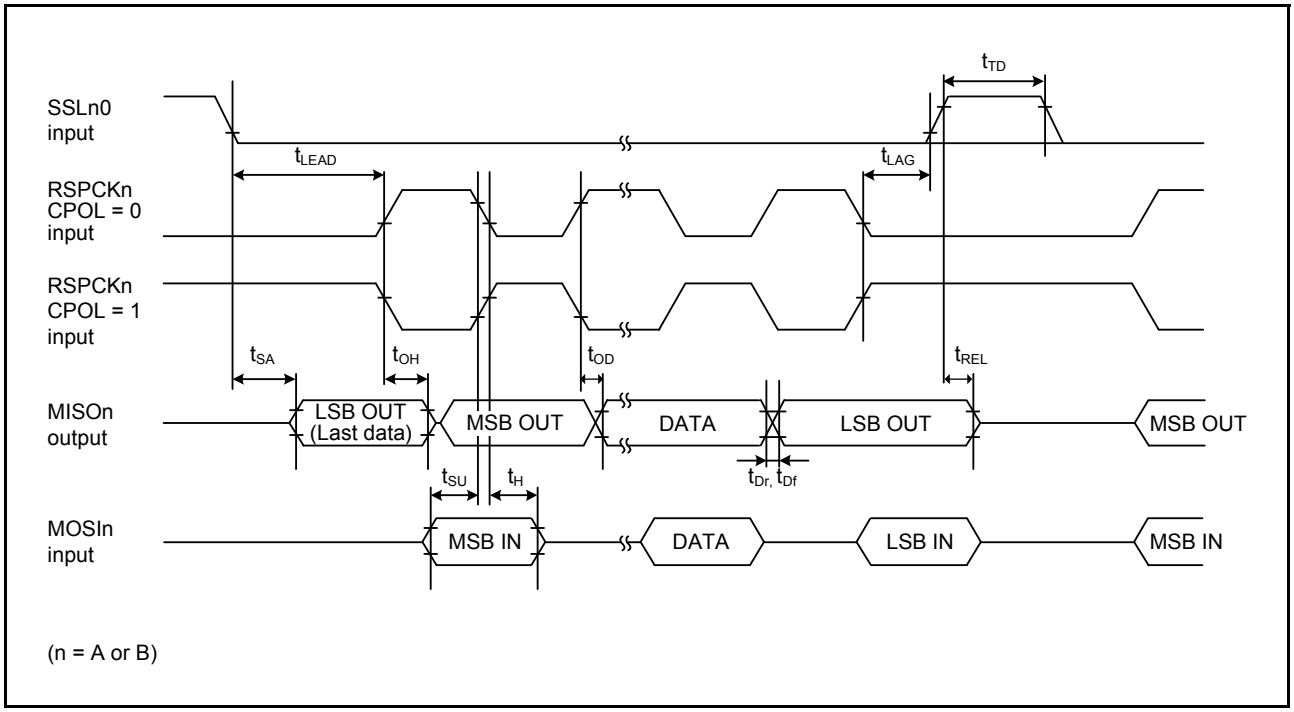


Figure 2.67 SPI timing (slave, CPHA = 1)

2.3.11 QSPI Timing

Table 2.41 QSPI timing

Conditions: VCC = 1.8 to 5.5 V
Conditions: Middle drive output is selected in the Port Drive Capability bit in PmnPFS register

Parameter			Symbol	Min	Max	Unit*1	Test conditions
QSPI	QSPCLK clock cycle		t_{QScyc}	2*4	48	t_{Pcyc}	Figure 2.68
	QSPCLK clock high-level pulse width		t_{QSWH}	t_{QScyc} × 0.4	-	ns	
	QSPCLK clock low-level pulse width		t_{QSWL}	t_{QScyc} × 0.4	-	ns	
	Data input setup time		t_{SU}	25	-	ns	Figure 2.69
	Data input hold time		t_{IH}	2	-	ns	
	SSL setup time		t_{LEAD}	(N + 0.5) × t_{Qscyc} - 15*2	(N + 0.5) × t_{Qscyc} + 100*2	ns	
	SSL hold time		t_{LAG}	(N + 0.5) × t_{Qscyc} - 15*3	(N + 0.5) × t_{Qscyc} + 100*3	ns	
	Data output delay	2.7 V or above	t_{OD}	-	14	ns	
		2.4 V or above		-	20		
		1.8 V or above		-	30		
	Data output hold time	2.7 V or above	t_{OH}	–3.3	-	ns	
		1.8 V or above		–10	-		
	Successive transmission delay		t_{TD}	1	16	t_{Qscyc}	

Note 1. t_{Pcyc}: PCLKA cycle.
Note 2. N is set to 0 or 1 in SFMSLD.
Note 3. N is set to 0 or 1 in SFMSHD.
Note 4. The upper limit of QSPCLK is 16MHz.

2.3.13 SSIE Timing

Table 2.43 SSIE timing
Conditions: VCC = 1.6 to 5.5 V

Parameter			Symbol	Min	Max	Unit	Test conditions
SSIE	AUDIO_CLK input frequency	2.7 V or above	t_{AUDIO}	-	25	MHz	-
		1.6 V or above		-	4		
	Output clock period		t_O	250	-	ns	Figure 2.71
	Input clock period		t_I	250	-	ns	
	Clock high pulse width	1.8 V or above	t_{HC}	100	-	ns	
		1.6 V or above		200	-		
	Clock low pulse width	1.8 V or above	t_{LC}	100	-	ns	
		1.6 V or above		200	-		
	Clock rise time		t_{RC}	-	25	ns	
	Data delay	2.7 V or above	t_{DTR}	-	65	ns	Figure 2.72, Figure 2.73
		1.8 V or above		-	105		
		1.6 V or above		-	140		
	Set-up time	2.7 V or above	t_{SR}	65	-	ns	
		1.8 V or above		90	-		
		1.6 V or above		140	-		
	Hold time		t_{HTR}	40	-	ns	
	SSITXD0 output delay from SSILRCK/SSIFS change time	1.8 V or above	t_{DTRW}	-	105	ns	Figure 2.74
		1.6 V or above		-	140		

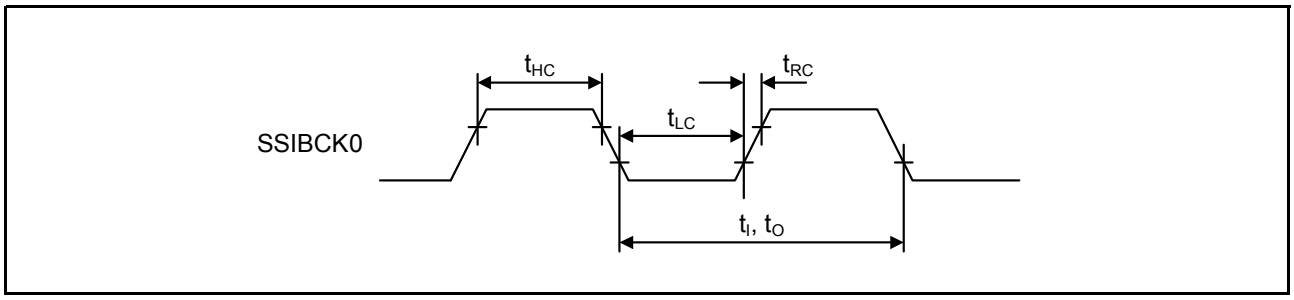


Figure 2.71 SSIE clock input/output timing

2.4 USB Characteristics

2.4.1 USBFS Timing

Table 2.46 USB characteristics

Conditions: VCC = VCC_USB = 3.0 to 3.6 V, Ta = -20 to +85°C (USBCLKSEL = 1), Ta = -40 to +105°C (USBCLKSEL = 0)

Parameter			Symbol	Min	Max	Unit	Test conditions
Input characteristics	Input high level voltage		V_{IH}	2.0	-	V	-
	Input low level voltage		V_{IL}	-	0.8	V	-
	Differential input sensitivity		V_{DI}	0.2	-	V	| USB_DP - USB_DM |
	Differential common mode range		V_{CM}	0.8	2.5	V	-
Output characteristics	Output high level voltage		V_{OH}	2.8	VCC_USB	V	I_{OH} = –200 µA
	Output low level voltage		V_{OL}	0.0	0.3	V	I_{OL} = 2 mA
	Cross-over voltage		V_{CRS}	1.3	2.0	V	Figure 2.77, Figure 2.78, Figure 2.79
	Rise time	FS	t_r	4	20	ns	
		LS		75	300		
	Fall time	FS	t_f	4	20	ns	
		LS		75	300		
	Rise/fall time ratio	FS	t_r/t_f	90	111.11	%	
		LS		80	125		
	Output resistance		Z_{DRV}	28	44	Ω	(Adjusting the resistance of external elements is not required.)
VBUS characteristics	VBUS input voltage		V_{IH}	VCC × 0.8	-	V	-
			V_{IL}	-	VCC × 0.2	V	-
Pull-up, pull-down	Pull-down resistor		R_{PD}	14.25	24.80	kΩ	-
	Pull-up resistor		R_{PUI}	0.9	1.575	kΩ	During idle state
			R_{PUA}	1.425	3.09	kΩ	During reception
Battery Charging Specification Ver 1.2	D+ sink current		I_{DP_SINK}	25	175	µA	-
	D– sink current		I_{DM_SINK}	25	175	µA	-
	DCD source current		I_{DP_SRC}	7	13	µA	-
	Data detection voltage		V_{DAT_REF}	0.25	0.4	V	-
	D+ source voltage		V_{DP_SRC}	0.5	0.7	V	Output current = 250 µA
	D– source voltage		V_{DM_SRC}	0.5	0.7	V	Output current = 250 µA

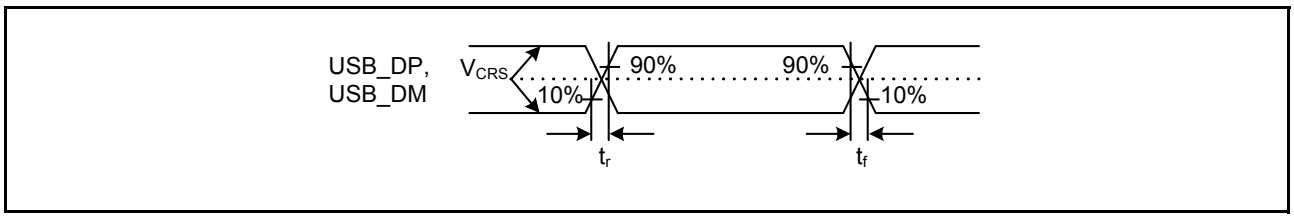


Figure 2.77 USB_DP and USB_DM output timing

2.7 TSN Characteristics

Table 2.60 TSN characteristics
Conditions: VCC = AVCC0 = 2.0 to 5.5 V

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Relative accuracy	-	-	±1.5	-	°C	2.4 V or above
	-	-	±2.0	-	°C	Below 2.4 V
Temperature slope	-	-	–3.65	-	mV/°C	-
Output voltage (at 25°C)	-	-	1.05	-	V	VCC = 3.3 V
Temperature sensor start time	t_{START}	-	-	5	µs	-
Sampling time	-	5	-	-	µs	-

2.8 OSC Stop Detect Characteristics

Table 2.61 Oscillation stop detection circuit characteristics

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Detection time	t_{dr}	-	-	1	ms	Figure 2.84

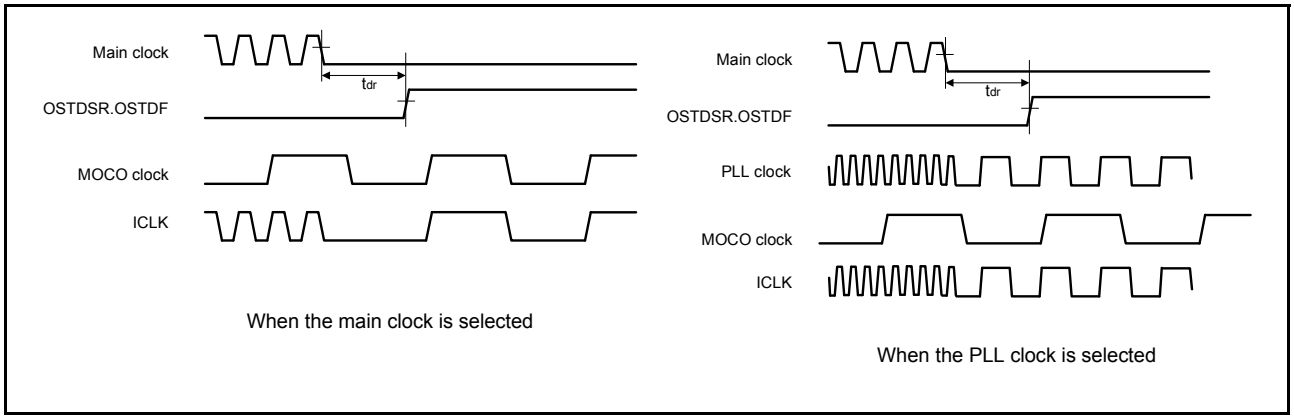


Figure 2.84 Oscillation stop detection timing

2.9 POR and LVD Characteristics

Table 2.62 Power-on reset circuit and voltage detection circuit characteristics (1)

Parameter		Symbol	Min	Typ	Max	Unit	Test conditions
Voltage detection level*1	Power-on reset (POR)	V_{POR}	1.27	1.42	1.57	V	Figure 2.85, Figure 2.86
	Voltage detection circuit (LVD0)*2	V_{det0_0}	3.68	3.85	4.00	V	Figure 2.87 At falling edge VCC
		V_{det0_1}	2.68	2.85	2.96		
		V_{det0_2}	2.38	2.53	2.64		
		V_{det0_3}	1.78	1.90	2.02		
		V_{det0_4}	1.60	1.69	1.82		
	Voltage detection circuit (LVD1)*3	V_{det1_0}	4.13	4.29	4.45	V	Figure 2.88 At falling edge VCC
		V_{det1_1}	3.98	4.16	4.30		
		V_{det1_2}	3.86	4.03	4.18		
		V_{det1_3}	3.68	3.86	4.00		
		V_{det1_4}	2.98	3.10	3.22		
		V_{det1_5}	2.89	3.00	3.11		
		V_{det1_6}	2.79	2.90	3.01		
		V_{det1_7}	2.68	2.79	2.90		
		V_{det1_8}	2.58	2.68	2.78		
		V_{det1_9}	2.48	2.58	2.68		
		V_{det1_A}	2.38	2.48	2.58		
		V_{det1_B}	2.10	2.20	2.30		
		V_{det1_C}	1.84	1.96	2.05		
		V_{det1_D}	1.74	1.86	1.95		
		V_{det1_E}	1.63	1.75	1.84		
		V_{det1_F}	1.60	1.65	1.73		
	Voltage detection circuit (LVD2)*4	V_{det2_0}	4.11	4.31	4.48	V	Figure 2.89 At falling edge VCC
		V_{det2_1}	3.97	4.17	4.34		
		V_{det2_2}	3.83	4.03	4.20		
		V_{det2_3}	3.64	3.84	4.01		

Note 1. These characteristics apply when noise is not superimposed on the power supply. When a setting causes this voltage detection level to overlap with that of the voltage detection circuit, it cannot be specified whether LVD1 or LVD2 is used for voltage detection.
Note 2. # in the symbol Vdet0_# denotes the value of the OFS1.VDSEL1[2:0] bits.
Note 3. # in the symbol Vdet1_# denotes the value of the LVDLVLR.LVD1LVL[4:0] bits.
Note 4. # in the symbol Vdet2_# denotes the value of the LVDLVLR.LVD2LVL[2:0] bits.

Table 2.63 Power-on reset circuit and voltage detection circuit characteristics (2)

Parameter		Symbol	Min	Typ	Max	Unit	Test conditions
Wait time after power-on reset cancellation	LVD0: enable	t_{POR}	-	1.7	-	ms	-
	LVD0: disable	t_{POR}	-	1.3	-	ms	-
Wait time after voltage monitor 0, 1, 2 reset cancellation	LVD0: enable*1	$t_{LVD0,1,2}$	-	0.6	-	ms	-
	LVD0: disable*2	$t_{LVD1,2}$	-	0.2	-	ms	-
Response delay*3		t_{det}	-	-	350	µs	Figure 2.85, Figure 2.86
Minimum VCC down time		t_{VOFF}	450	-	-	µs	Figure 2.85, VCC = 1.0 V or above
Power-on reset enable time		$t_{W(POR)}$	1	-	-	ms	Figure 2.86, VCC = below 1.0 V
LVD operation stabilization time (after LVD is enabled)		$t_{d(E-A)}$	-	-	300	µs	Figure 2.88, Figure 2.89
Hysteresis width (POR)		V_{PORH}	-	110	-	mV	-
Hysteresis width (LVD0, LVD1, and LVD2)		V_{LVH}	-	60	-	mV	LVD0 selected
			-	100	-		V_{det1_0} to V_{det1_2} selected
			-	60	-		V_{det1_3} to V_{det1_9} selected
			-	50	-		V_{det1_A} or V_{det1_B} selected
			-	40	-		V_{det1_C} or V_{det1_F} selected
			-	60	-		LVD2 selected

Note 1. When OFS1.LVDAS = 0.
Note 2. When OFS1.LVDAS = 1.
Note 3. The minimum VCC down time indicates the time when VCC is below the minimum value of voltage detection levels V_{POR}, Vdet0, Vdet1, and Vdet2 for the POR/LVD.

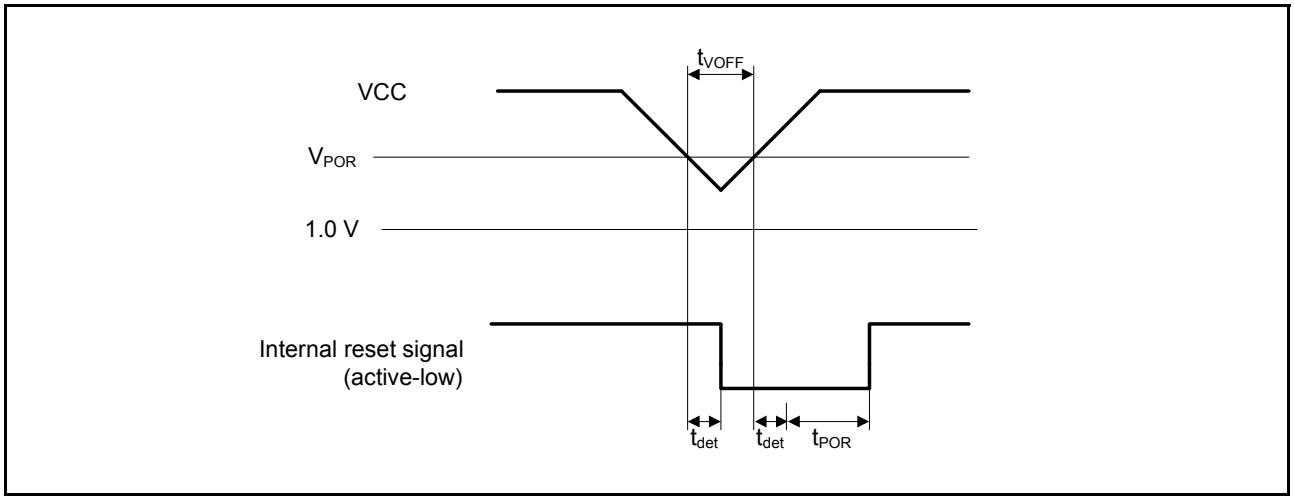


Figure 2.85 Voltage detection reset timing

2.12.2 Internal Voltage Boosting Method

[1/3 Bias Method]

Table 2.70 Internal voltage boosting method LCD characteristics
Conditions: VCC = 1.8 V to 5.5 V

Parameter	Symbol	Conditions		Min	Typ	Max	Unit	Test conditions
LCD output voltage variation range	V_{L1}	C1 to C4*1 = 0.47 µF	VLCD = 04h	0.90	1.0	1.08	V	-
			VLCD = 05h	0.95	1.05	1.13	V	-
			VLCD = 06h	1.00	1.10	1.18	V	-
			VLCD = 07h	1.05	1.15	1.23	V	-
			VLCD = 08h	1.10	1.20	1.28	V	-
			VLCD = 09h	1.15	1.25	1.33	V	-
			VLCD = 0Ah	1.20	1.30	1.38	V	-
			VLCD = 0Bh	1.25	1.35	1.43	V	-
			VLCD = 0Ch	1.30	1.40	1.48	V	-
			VLCD = 0Dh	1.35	1.45	1.53	V	-
			VLCD = 0Eh	1.40	1.50	1.58	V	-
			VLCD = 0Fh	1.45	1.55	1.63	V	-
			VLCD = 10h	1.50	1.60	1.68	V	-
			VLCD = 11h	1.55	1.65	1.73	V	-
			VLCD = 12h	1.60	1.70	1.78	V	-
			VLCD = 13h	1.65	1.75	1.83	V	-
Doubler output voltage	V_{L2}	C1 to C4*1 = 0.47 µF		$2 \times V_{L1}$ - 0.1	$2 \times V_{L1}$	$2 \times V_{L1}$	V	-
Tripler output voltage	V_{L4}	C1 to C4*1 = 0.47 µF		$3 \times V_{L1}$ - 0.15	$3 \times V_{L1}$	$3 \times V_{L1}$	V	-
Reference voltage setup time*2	t_{VL1S}			5	-	-	ms	Figure 2.93
LCD output voltage variation range*3	t_{VLWT}	C1 to C4*1 = 0.47 µF		500	-	-	ms	

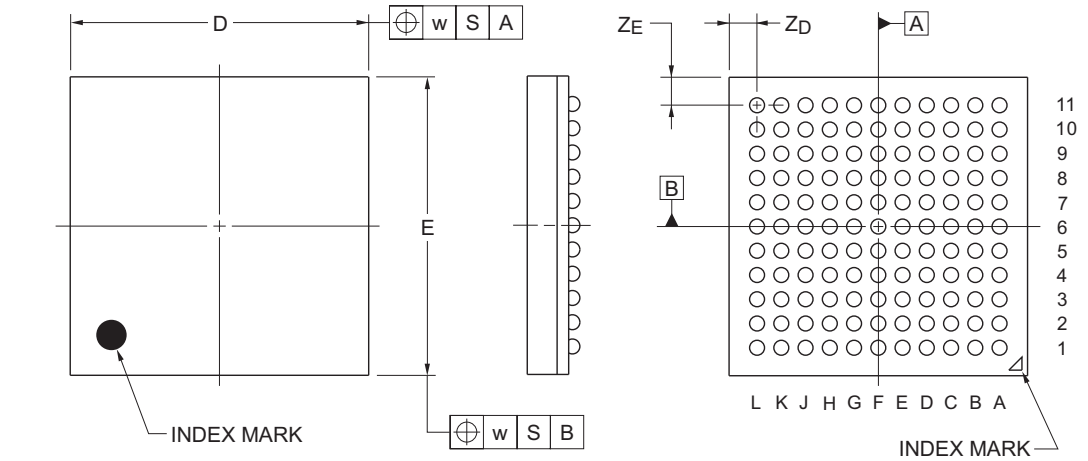
Note 1. This is a capacitor that is connected between voltage pins used to drive the LCD.
C1: A capacitor connected between CAPH and CAPL
C2: A capacitor connected between VL1 and GND
C3: A capacitor connected between VL2 and GND
C4: A capacitor connected between VL4 and GND
C1 = C2 = C3 = C4 = 0.47 µF ± 30%

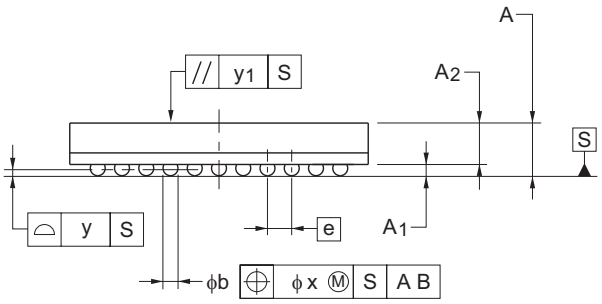
Note 2. This is the time required to wait from when the reference voltage is specified using the VLCD register (or when the internal voltage boosting method is selected (by setting the MDSET[1:0] bits in the LCDM0 register to 01b) if the default value reference voltage is used) until voltage boosting starts (VLCON = 1).

Note 3. This is the wait time from when voltage boosting is started (VLCON = 1) until display is enabled (LCDON = 1).

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
P-LFBGA121-8x8-0.65	PLBG0121JA-A	—	0.15

Unit: mm





Reference Symbol	Dimensions in millimeters		
	Min	Nom	Max
D	7.90	8.00	8.10
E	7.90	8.00	8.10
w	—	0.20	—
A	1.11	1.21	1.31
A_1	0.25	0.30	0.35
A_2	—	0.91	—
e	—	0.65	—
b	0.35	0.40	0.45
x	—	0.08	—
y	—	0.10	—
y_1	—	0.20	—
Z_D	—	0.75	—
Z_E	—	0.75	—

Figure 1.3 BGA 121-pin